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What randomized benchmarking actually measures

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Randomized benchmarking (RB) is widely used to measure an error rate of a set of quantum gates, by performing random circuits that would do nothing if the gates were perfect. In the limit of no finite-sampling error, the exponential decay rate of the observable survival probabilities, versus circuit length, yields a single error metric r. For Clifford gates with arbitrary small errors described by process matrices, r was believed to reliably correspond to the mean, over all Cliffords, of the *average gate infidelity* (AGI) between the imperfect gates and their ideal counterparts. We show that this quantity is not a well-defined property of a physical gateset. It depends on the *representations* used for the imperfect and ideal gates, and the variant typically computed in the literature can differ from r by orders of magnitude. We present new theories of the RB decay that are accurate for all small errors describable by process matrices, and show that the RB decay curve is a simple exponential for all such errors. These theories allow explicit computation of the error rate that RB measures (r), but as far as we can tell it does not correspond to the infidelity of a physically allowed (completely positive) representation of the imperfect gates.

Randomized benchmarking (RB) [1-22] is a simple and efficient protocol for measuring an average error rate of a quantum information processor (QIP), and is among the most commonly used experimental methods for characterizing QIPs [23–33]. In its purest form, RB consists of: (1) performing many randomly chosen sequences of Clifford gates that ought to return the QIP to its initial state; (2) measuring at the end of each sequence to see whether the QIP "survived" (i.e., returned to its initial state); and (3) plotting the observed survival probabilities vs. sequence length and fitting this to an exponential decay curve. The decay rate of the survival probability is – up to a dimensionality constant, and neglecting any finite-sampling error – the "RB number" (r). RB experiments estimate r, which is used as a metric for judging the processor's performance.

The r that RB measures has a clear operational definition, but it is not clear how it relates to common metrics – i.e., what it is that RB measures. In QIP theory, the ideal "target" operations and the imperfect asimplemented operations are usually represented by process matrices, a.k.a. CPTP (completely positive, tracepreserving) maps. The generally accepted theory behind RB [5-8] suggests that r is approximately equal to the average, over all n-qubit Cliffords, of the average gate *infidelity* [AGI, Eq. (1)] between the imperfect Cliffords and their ideal counterparts. We call this quantity the average gateset infidelity [AGsI, Eq. (2)] and denote it by ϵ . It has been widely believed that $r \approx \epsilon$ whenever the errors in the gates are small, and describable by process matrices [5-17]. In this Letter, we show that r and ϵ can differ by orders of magnitude (Fig. 1). This happens because ϵ is not a well-defined property of a physical QIP. Instead, ϵ is a property of the *representation* used to describe the gates, and depends strongly on which of several equivalent and indistinguishable representations



FIG. 1. An example of the discrepancy between r and the literature definition for ϵ . Here the errors are coherent rotations proportional to θ (see main text). For $\theta \ll 1$ the errors are small, and prior RB theory [5–8] predicts that $r \approx \epsilon$. Main plot: the curve predicted by prior RB theory [5, 6] (for $\theta = 0.1$) is inconsistent with simulated RB data, which is accurately predicted by the theory introduced herein. Inset: ϵ , estimates of r from simulated data, and the r predicted by our theory (r_{γ}) , as θ is varied.

is used. We provide a new theory for the RB decay that is representation-independent, proves that the RB decay is always exponential when the noise is described by process matrices, and gives an efficient representationindependent approximate formula for r with small error bars.

Experimental RB: The basic RB protocol (extensions exist [9–13]) was summarized above. Complete details can be found in Refs. [5–8], and in the Supplementary Material [34]. As in most experiments [23–31], we consider benchmarking an implementation of the *n*-qubit Clifford gates with $n \ge 1$. The standard way to estimate r from RB data is to fit the average of the sampled survival probabilities (P_m) , for many sequence lengths m, to the model $P_m = A + (B + Cm)p^m$, where A, B, C, and p are fit parameters [5–8]. The estimate of p, denoted \hat{p} , gives an estimate of r as $\hat{r} = (d-1)(1-\hat{p})/d$, where $d = 2^n$. It

is common to fix C = 0, but Magesan *et al.* [5, 6] suggest that fitting C may be necessary when the error varies from gate to gate.

Theory of RB: The average survival probabilities P_m are unambiguously real and experimentally accessible. And r is equally well-defined, as long as the P_m decay exponentially with m. The motivation for further analysis – for a *theory* of RB – is primarily to answer two questions. First, under what circumstances does P_m decay exponentially? Second, when it does, what is r? That is, to what property of the imperfect gates does r correspond? Building such a theory requires specifying a model for the operations used in RB.

These operations comprise: (1) a set of gates; (2) a set of state preparations; and (3) a set of measurements, which together form a *physical gateset*. A model associates them with mathematical objects that can be used to compute P_m . If each operation is independent of all external contexts – e.g., time, external fields, ancillary qubits – then each gate can be represented by a process matrix G_i , each state preparation by a density operator ρ_i , and each measurement by a positive operatorvalued measure (POVM) $\mathcal{M}_k = \{E_{k,l}\}$. Probabilities of events are given by Born's Rule: $\Pr(E_{k,l} | \rho_i, G_i) =$ $\operatorname{Tr}[E_{k,l}G_i\rho_i]$. In this commonly used model for analyzing RB, an as-built processor with an imperfect physical gateset can be represented by some $\tilde{\mathcal{G}} = \{\tilde{G}_i, \tilde{\rho}_i, \tilde{E}_{k,l}\},\$ and an idealized perfect device by some $\mathcal{G} = \{G_i, \rho_i, E_{k,l}\}$. Since r is independent of the state preparation and measurement [5, 6], we will usually only need representations of the imperfect and ideal Cliffords, denoted $\mathcal{C} = \{C_i\}$ and $\mathcal{C} = \{C_i\}$, respectively.

RB theory is clear when the gateset has gateindependent errors; which means that there is a process matrix Λ such that each imperfect Clifford can be represented as $\tilde{C}_i = \Lambda C_i$. In this situation, r is exactly equal to the average gate infidelity (AGI) between Λ and the identity process matrix 1 [5]. The AGI between process matrices \tilde{G} and G is simply $1 - \bar{F}$, where

$$\bar{F}(\tilde{G},G) \coloneqq \int d\psi \operatorname{Tr}\left(\tilde{G}[|\psi\rangle\langle\psi|]G[|\psi\rangle\langle\psi|]\right).$$
(1)

But a general theory of RB needs to address the more likely case of gate-*dependent* errors, where $\tilde{C}_i = \Lambda_i C_i$. A starting point is the observation that, for gateindependent errors, every imperfect Clifford has the same AGI with its ideal counterpart: $\bar{F}(\tilde{C}_i, C_i) = \bar{F}(\Lambda, \mathbb{1})$. So, a plausible generalization of AGI to gate-dependent errors is its *average* over all Cliffords:

$$\epsilon(\tilde{\mathcal{C}}, \mathcal{C}) \coloneqq \operatorname{avg}_i \left[1 - \bar{F}(\tilde{C}_i, C_i) \right], \tag{2}$$

a quantity we call the *average gateset infidelity* (AGsI).

An extensive literature suggests or argues that $r \approx \epsilon$ [5– 17] for "weakly gate-dependent" errors [5, 6] – i.e., when all the error maps $\Lambda_i = \tilde{C}_i C_i^{-1}$ are close to their average.



FIG. 2. A comparison between simulated RB data and the decay curve predicted by prior RB theory [5, 6] for a gateset with small unitary errors. The blue shaded region depicts the range within which the RB decay is guaranteed to fall by the theorems in Ref. [5, 6], in the limit of many samples.

More precisely, when $\delta := \|\Lambda_i - \bar{\Lambda}\|_{1 \to 1}^H \ll 1$ for all i [5, 6], where $\bar{\Lambda} := \operatorname{avg}_i[\Lambda_i]$ is the average error map, and $\|\cdot\|_{1 \to 1}^H$ is the Hermitian 1-to-1 norm [6]. Since this is true whenever the Λ_i are all close to 1, it holds for all small errors. However, r and ϵ can actually differ by orders of magnitude, for simple and realistic noise models. Consider a simple 1-qubit example involving Cliffords compiled into two "primitive" gates.

Example 1: The ideal primitive gates are represented by $G_x = R(\sigma_x, \pi/2)$ and $G_y = R(\sigma_y, \pi/2)$, where $R(H, \theta)[\rho] := \exp(-i\theta H/2)\rho \exp(i\theta H/2)$. Any 1-qubit Clifford can be compiled into G_x and G_y . The *imperfect* primitives are represented by $\tilde{G}_x = R(\sigma_z, \theta)G_x$ and $\tilde{G}_y = R(\sigma_z, \theta)G_y$ with $\theta \ll 1$, which corresponds to a small systematic detuning or timing error.

We simulated RB with Cliffords compiled into these imperfect gates and observed $r \ll \epsilon$. For $\theta = 0.1$, the theory predicts $\epsilon \approx 10^{-3}$, but we observed $\hat{r} \approx 10^{-5}$ (Fig. 1). Varying θ (Fig. 1, inset) shows that $r \propto \theta^4$, while $\epsilon \propto \theta^2$. As the errors become small, the ratio ϵ/r diverges.

This example lies within the domain of standard RB theory – the errors are small and only weakly gatedependent (as defined in Refs. [5, 6]) – and it does not contradict the technical results of Refs. [5, 6], that link r to ϵ . Refs. [5, 6] include error bounds that bound the difference between actual and predicted RB decay curves. These bounds, which we plot for Example 1 in Fig. 2, are sufficiently loose that they do not significantly constrain ϵ/r . A complete description of our simulation methodology is provided in the Supplementary Material [34].

Understanding the discrepancy: The discrepancy between r and ϵ has a simple but subtle explanation: RB, like all experiments, probes properties of a *physical* QIP, not of a *model* for it. Although a physical QIP's gates may be accurately represented by a fixed set of process matrices, that representation is not unique. The RB error rate r is a property of the physical gates, and therefore representation-independent. But ϵ , as conventionally defined, is not.

Two representations of a physical gateset are equivalent if they cannot be distinguished by any experiment. More precisely, representations \mathcal{G} and \mathcal{G}' are equivalent iff they predict the same probabilities for *every* quantum circuit. Equivalent representations are easy to construct. If $\mathcal{G} = \{G_i, \rho_j, E_{k,l}\}$ accurately represents a QIP, then so does

$$\mathcal{G}(M) = \{ MG_i M^{-1}, M(\rho_j), M^{-1}(E_{k,l}) \}, \qquad (3)$$

where M is any invertible linear map, which we call a gauge transformation [35–38]. If f is an observable property of the QIP that can be computed from a model \mathcal{G} , then $f(\mathcal{G})$ must be the same for all equivalent representations. So observable properties like r must correspond to gauge-invariant functions: $f(\mathcal{G}) = f(\mathcal{G}(M))$ for all M.

The AGsI defined in Eq. (2) is not gauge-invariant. It depends on the representations for the physical and perfect gatesets. If \tilde{C} and C are representations for the imperfect and ideal Cliffords respectively, then $\tilde{C}(M)$ and C(N) are equivalent representations, for arbitrary invertible M and N. The AGsI has a continuum of values as Mand N are varied, and this is still true if we (arbitrarily) fix either representation.

Transforming the perfect and imperfect Cliffords in the same way (i.e., M = N above) leaves the AGsI unchanged. So, we can define a gauge-invariant AGsI by comparing \tilde{C} not to the usual fixed representation of the Cliffords C, but to a C-dependent representation of them, $C_{\tilde{C}}$, that satisfies $C_{\tilde{C}(M)} = C_{\tilde{C}}(M)$. For example, we could define the AGsI with respect to the representation of the perfect Cliffords that is "closest" to the process matrices representing the imperfect Cliffords. If we do so, the assertion that $r \approx \epsilon$ is not wrong, but ambiguous; it requires a unique definition for the "closest" representation of the Cliffords. We return to this at the end of the Letter.

As far as we can tell, ϵ has not been defined or calculated in a representation-independent way in the literature. It is generally defined by: (1) taking C as the automorphism group of the Pauli matrices; (2) taking the imperfect gateset to be $\tilde{C} = \{\Lambda_i C_i\}$ where the Λ_i describe the "relevant error process"; and (3) calculating the AGsI (Eq. 2) between \tilde{C} and the already-defined matrices C. This procedure, which we followed in our example above, is explicit in the RB simulations of Refs. [8, 16] and is the most natural reading of the foundational RB papers by Magesan *et al.* [5, 6].

Example 2: A perfect Clifford gateset $\tilde{C} = C$ has an AGsI to C of $\epsilon(\tilde{C}, C) = 0$. But if U is a unitary and $\mathcal{U}[\rho] \coloneqq U\rho U^{\dagger}$, then $\tilde{C}(\mathcal{U})$ is an equivalent representation of the gateset with generally non-zero AGsI.

Example 1 is actually very similar to Example 2. The imperfect primitive gates in Example 1, \tilde{G}_x and \tilde{G}_y , are almost gauge-equivalent to their perfect counterparts. Some algebra shows that $\tilde{G}_{x/y}(\rho) = U_{x/y}\rho U_{x/y}^{\dagger}$ where $U_{x/y} = \exp(-i\phi(\hat{v}_{x/y}\cdot\vec{\sigma})/2), \phi = \pi/2 + O(\theta^2)$, and $\hat{v}_x\cdot\hat{v}_y = 0 + O(\theta^2)$. So at $O(\theta)$ the \tilde{G}_x and \tilde{G}_y gates induce rotations by $\pi/2$ around orthogonal axes. Hence, there exists some \mathcal{U} with $\mathcal{U}[\rho] = U\rho U^{\dagger}$ for unitary U such that $\mathcal{U}\tilde{G}_{x/y}\mathcal{U}^{-1} = R(\hat{w}_{x/y} \cdot \vec{\sigma}, \varphi_{x/y})G_{x/y}$ where $\varphi_{x/y} = O(\theta^2)$ and $\hat{w}_{x/y}$ are some unit vectors. In this representation, the Clifford error maps $\Lambda_i = \tilde{C}_i C_i^{-1}$ are unitary rotations by $O(\theta^2)$, which suggests an RB number of $r = O(\theta^4)$, as observed. Although the $O(\theta)$ detuning error is real and physical, its effect on *these* gates is, at $O(\theta)$, equivalent to a gauge transformation. So, in *all* circuits consisting of only these gates, it behaves like a coherent error with a rotation angle of $O(\theta^2)$.

New theories for the RB decay: We would like to know what property of a physical gateset RB is measuring, and to have an accurate, efficient formula for $r({\tilde{C}_i})$. To this end, we now present new theories for the RB decay that are representation-independent and highly accurate.

The average survival probability over all RB sequences of length m is

$$P_m = \frac{1}{|\mathcal{C}|^m} \sum_{\boldsymbol{s}} \operatorname{Tr}(E\tilde{C}_{\boldsymbol{s}^{-1}}\tilde{C}_{\boldsymbol{s}_m} \dots \tilde{C}_{\boldsymbol{s}_1}(\rho)), \qquad (4)$$

where E and ρ are the (imperfect) measurement and state preparation, $C_{s^{-1}}$ is the Clifford that inverts the first mCliffords, $s \in [1..|\mathcal{C}|]^m$, and $|\mathcal{C}|$ is the order of the Clifford group. The map $S_m = \operatorname{avg}_s[\tilde{C}_{s^{-1}}\tilde{C}_{s_m}\ldots\tilde{C}_{s_1}]$ can be written as $S_m = |\mathcal{C}|\bar{v}^T \mathscr{R}^{m+1}\bar{v}$, where $\bar{v} = (\mathbb{1}, \mathbb{0}, \ldots, \mathbb{0})^T$, $\mathbb{1}$ and $\mathbb{0}$ are the *n*-qubit identity and "zero" superoperators $(\mathbb{0}(\rho) = 0)$ respectively, and

$$\mathscr{R} = \frac{1}{|\mathcal{C}|} \begin{pmatrix} \tilde{C}_{1 \to 1} & \tilde{C}_{2 \to 1} & \cdots & \tilde{C}_{|\mathcal{C}| \to 1} \\ \tilde{C}_{1 \to 2} & \tilde{C}_{2 \to 2} & \cdots & \tilde{C}_{|\mathcal{C}| \to 2} \\ \vdots & \vdots & \ddots & \vdots \\ \tilde{C}_{1 \to |\mathcal{C}|} & \tilde{C}_{2 \to |\mathcal{C}|} & \cdots & \tilde{C}_{|\mathcal{C}| \to |\mathcal{C}|} \end{pmatrix},$$
(5)

where $C_{j \to k} = C_j^{-1}C_k$ and $\tilde{C}_{j \to k}$ is the corresponding imperfect Clifford. It follows that $P_m = |\mathcal{C}| \operatorname{Tr}(E(\vec{v}^T \mathscr{R}^{m+1} \vec{v})(\rho))$, and so

$$P_m = \sum_i \alpha_i \lambda_i^{m+1},\tag{6}$$

where $\{\lambda_i\}$ are the $4^n |\mathcal{C}|$ eigenvalues of \mathscr{R} , *n* is the number of qubits, and $\{\alpha_i\}$ are constants depending on ρ , *E*, and the eigenvectors of \mathscr{R} .

This exact expression for the RB decay curve can be calculated efficiently in m (unlike exhaustive averaging over $|\mathcal{C}|^{m-1}$ sequences). However, it is intractable for n > 1 qubits, and does not explain why decays with a functional form of $A+Bp^m$ are normally observed in practice. We therefore make a small approximation.

Because $\tilde{C}_{s^{-1}} = (\bar{\Lambda} + \Delta_{s^{-1}})C_{s_1}^{-1} \dots C_{s_m}^{-1}$, where $\Delta_i = \Lambda_i - \bar{\Lambda}$, we can rewrite Eq. (4) as

$$P_m = \frac{1}{|\mathcal{C}|^m} \sum_{\boldsymbol{s}} \operatorname{Tr}(E\bar{\Lambda}C_{s_1}^{-1} \dots C_{s_m}^{-1}\tilde{C}_{s_m} \dots \tilde{C}_{s_1}(\rho)) + \tilde{\delta}_m.$$
(7)

Therefore $P_m = \text{Tr}(E\bar{\Lambda}[\mathscr{L}^m(\mathbb{1})](\rho)) + \tilde{\delta}_m$, where

$$\mathscr{L}(\mathcal{E}) = \operatorname{avg}_i[C_i^{-1}\mathcal{E}\tilde{C}_i], \qquad (8)$$

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is a linear map on superoperators (a "superduperoperator" [39]). Hence, $P_m = \sum_i \omega_i \gamma_i^m + \tilde{\delta}_m$, where $\{\gamma_i\}$ are the 16ⁿ eigenvalues of \mathscr{L} , and $\{\omega_i\}$ depend on ρ , E, $\bar{\Lambda}$, and the eigenvectors of \mathscr{L} . The $\{\gamma_i\}$ are representationindependent. In the Supplementary Material [34] we prove that $\tilde{\delta}_m$ satisfies $|\tilde{\delta}_m| \leq \delta_{\diamond} \equiv \frac{1}{2} \operatorname{avg}_i ||\Lambda_i - \bar{\Lambda}||_{\diamond}$. Because the Λ_i are representation-dependent, the size of δ_{\diamond} depends on the representation-dependent, the size of δ_{\diamond} depends on the representations, $|\tilde{\delta}_m| \leq \delta_{\diamond}^{\min}$ bound holds for any CPTP representations, $|\tilde{\delta}_m| \leq \delta_{\diamond}^{\min}$ with δ_{\diamond}^{\min} the minimum of δ_{\diamond} over all CPTP representations of the gatesets.

If there exists a representation in which the errors are gate-independent ($\tilde{C}_i = \Lambda C_i$ for all *i* and some Λ), then $\delta_{\diamond}^{\min} = 0$ and the RB decay is exactly described by \mathscr{L} . Because the Cliffords are a unitary 2-design [3], \mathscr{L} has only three distinct eigenvalues in this case: 1, γ , and 0 (0 has a degeneracy of $16^n - 2$). The RB decay is then exactly described by $P_m = \omega_0 + \omega_1 \gamma^m$. This recovers the exact RB theory for gate-independent error maps [5, 6].

Small errors are a small perturbation away from the case of no error ($\gamma = 1$), and cause similarly small perturbations of the eigenvalues. Hence, for any small errors, $\gamma_0 = 1$ (as 1 is always an eigenvalue of \mathscr{L}), γ_1 satisfies $1 - \gamma_1 \ll 1$, and $|\gamma_i| \ll 1$ for all i > 1. As such,

$$P_m = \omega_0 + \omega_1 \gamma^m + \delta_m, \tag{9}$$

where $\gamma = \gamma_1$, $|\delta_m| \leq \delta_{\diamond}^{\min} + \kappa_m$, and $\kappa_m = |\omega_2 \gamma_2^m + \omega_3 \gamma_3^m + \dots|$ is an exponentially decreasing function of m. Hence, for $m \gg 1$ the RB decay curve is well approximation by the functional form $P_m = A + Bp^m$. Therefore, the p obtained from fitting RB data to $P_m = A + Bp^m$ is an estimate of γ , the second largest eigenvalue of \mathscr{L} . Similarly, as r is given by r = (d-1)(1-p)/d, r is approximately an estimate of $r_{\gamma} \equiv (d-1)(1-\gamma)/d$. That is, $r = r_{\gamma} + \delta_r$ with $\delta_r \ll 1$ a small correction factor. Fig. 1 demonstrates this for the gateset of Example 1.

To our knowledge, this is the first proof that the RB decay curve is guaranteed to always be exponential for small errors that can be described by CPTP maps – including gate-dependent errors. This indicates that the model $P_m = A + (B + Cm)p^m$ is not necessary. Fitting it should always yield $\hat{C} \approx 0$, so estimating C is not likely to help quantify gate-dependence (see suggestion in Refs. [5, 6]). Instead, our results show that significant non-exponential decay is a clear symptom of non-Markovianity (e.g., time dependence).

We now return to a question raised earlier: Are there natural representations of the perfect and imperfect gatesets in which $\epsilon = r$? "Natural" is important, because ϵ varies so widely over representations. An absurd answer would be to compute r and then search over *all* representations of a gateset to find one in which $\epsilon = r$. The most obvious reasonable option is to arbitrarily fix a CPTP representation of the perfect gateset and to choose the representation of the imperfect gateset in which the gates are all CPTP and ϵ is minimal (ϵ can always be made large by choosing a "bad" representation – see Example 2). This defines a new and gauge-invariant AGsI $\epsilon_{\min} \coloneqq \min_M[\epsilon(\tilde{\mathcal{C}}(M), \mathcal{C})]$, with the minimization restricted such that the gates in $\tilde{\mathcal{C}}(M)$ are CPTP. But ϵ_{\min} does *not* exactly correspond to r, as it can be strictly *less* than r (see Supplementary Material [34]).

After the initial version of this Letter appeared, Wallman [40] published an independent analysis of RB. Based on a different representation of the \mathscr{L} operator, Wallman's theory also derives an exponential decay at the same rate γ derived here, but proves a tighter error bound that decays exponentially with m, confirming that the RB decay is completely described by γ , and δ_r is negligible in $r = r_{\gamma} + \delta_r$. Wallman's construction implies that there exists a representation of the imperfect gates for which $\epsilon = r$. To prove this, let $\mathscr{L}'(\mathcal{E}) = \operatorname{avg}_i[\tilde{C}_i \mathcal{E} C_i^{-1}]$. \mathscr{L}' has the same spectrum as \mathscr{L} . Wallman [40] gives an explicit construction of a superoperator \mathcal{L} that satisfies $\mathscr{L}'(\mathcal{L}) = \mathcal{L}\mathcal{D}_{\gamma}$, where \mathcal{D}_{λ} is a depolarizing channel $(\mathcal{D}_{\lambda}(\rho) = (1-\lambda)1/d + \lambda \rho)$. Now, consider the particular representation of the imperfect Cliffords $\hat{\mathcal{C}}(\mathcal{L}^{-1})$ = $\{\mathcal{L}^{-1}\tilde{C}_i\mathcal{L}\}\$. Some simple algebra (see Supplementary Material [34]) shows that $r_{\gamma} = \epsilon(\tilde{\mathcal{C}}(\mathcal{L}^{-1}), \mathcal{C})$. So there is an explicitly calculable representation of the gateset that makes $\epsilon = r$. However, the gates in this representation are not generally completely positive, which makes it hard to consider this gauge "natural" (non-CP gauge choices can even make $\epsilon < 0$).

Conclusions: It is surprisingly nontrivial to relate the RB error rate r – a well-defined, representationindependent property of a physical QIP's gates – to the process matrices describing those gates, and identify what property it corresponds to. The simple relationship for gate-*independent* errors, where r equals the average gateset infidelity (AGsI, ϵ) between imperfect and perfect Cliffords, obscures the complexity of the general case. AGsI can be orders of magnitude larger than r unless the right representations are used. This has serious practical consequences, as shown by Example 1 and some of the results in Ref. [8], where $r \ll \epsilon$ for experimentally plausible error models.

Our analysis indicates that RB is even more stable and reliable than indicated by previous work [5, 6, 8]; P_m decays exponentially (without higher-order corrections of the form mp^m) for all small errors describable by process matrices, including coherent errors. We established this by introducing a new, accurate, theory for the RB decay curve that associates r with a calculable, representationindependent property of the physical gateset. Subsequent results by Wallman [40] allow us to observe that this quantity *is* an AGsI, for at least one representation of the imperfect gates, but in this representation the gate process matrices are generally unphysical (not completely positive). Since current theories for many extended RB protocols, such as interleaved [9], dihedral [16, 17], and unitarity [7] RB, rely on representation-dependent techniques, it is an interesting open question whether they can be reformulated in a representation-independent way as we did here with basic RB.

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